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**(PTO ASSISTANCE)**

Application : <u>10/774,515</u>	Examiner : <u>Dolan</u>	GAU : <u>2813</u>
From: <u>DP</u>	Location: <u>IDC</u> FMF FDC	Date: <u>8/18/05</u>
Tracking #: <u>6121698</u>		Week Date: <u>7/4/2005</u>

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<input type="checkbox"/> IIFW	_____	<input type="checkbox"/> Fees
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<input type="checkbox"/> OATH	_____	
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[RUSH] MESSAGE: 1449 → pages 12-15 of 24 dated 12-14-2001  
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# FAX TRANSMISSION



**DATE:** August 29, 2005  
**CLIENT NO.:** M4065.0697/P697-A, U.S. Patent Application No. 10/774,515  
**MESSAGE TO:** Ms. Rory Burch  
**COMPANY:** U.S. Patent and Trademark Office, Office of Publications  
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**PHONE:** (703) 305-0333, ext. 135  
**FROM:** James Soo-Chul Derry  
**PHONE:** (202) 777-2598

**PAGES (Including Cover Sheet):** 5 **HARD COPY TO FOLLOW:** ☐ YES ☒ NO

**MESSAGE:** U.S. Patent Application No.: 10/774,515

As requested, enclosed are enlarged copies of pages 12-15 of the IDS and Forms-1449 that were submitted to the PTO on February 10, 2004. If you have any additional comments or questions, please contact me at the above-referenced number.

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DSMDB.1974092.1

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PATENT AND TRADEMARK OFFICEATTY. DOCKET NO.  
M122-1527SERIAL NO.  
09/797,635LIST OF ART CITED BY APPLICANT  
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John T. Moore et al.FILING DATE  
March 1, 2001GROUP  
2813

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						Yes	No
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**SERIAL NO.**  
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						Yes	No
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